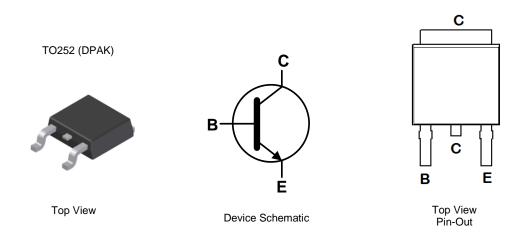


Features

- BV_{CEO} > 460V
- BV_{CES} > 700V
- BV_{EBO} > 9V
- I_C = 1.5A High Continuous Collector Current
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: TO252
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.34 grams (Approximate)



Ordering Information (Note 4)

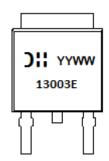
Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXT13003EK-13	Standard	13003E	13	16	2,500
Notes: 1. No purposely added lead, Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.					

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



13003E = Product Type Marking Code **JII** = Manufacturer's Code Marking YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)

Lead-free.



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V _{BE} = 0V)	V _{CES}	700	V
Collector-Emitter Voltage	V _{CEO}	460	V
Emitter-Base Voltage	V _{EBO}	9	V
Continuous Collector Current	Ι _C	1.5	А
Peak Pulse Collector Current (Note 5)	ICM	3	А
Continuous Base Current	IB	0.75	А
Peak Pulse Base Current (Note 5)	I _{BM}	1.5	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		3.9		
Power Dissinction	(Note 7)	Б	2.5	w	
Power Dissipation	(Note 8)	P _D	2.1		
	(Note 9)		1.6		
	(Note 6)		32		
Thermal Resistance, Junction to Ambient Air	(Note 7)	Р	51		
Thermal Resistance, Junction to Ambient An	(Note 8)	R _{θJA}	59	°C/W	
	(Note 9)		80		
Thermal Resistance, Junction to Leads	(Note 10)	R _{0JL}	3		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	۵°		

ESD Ratings (Note 11)

Notes:

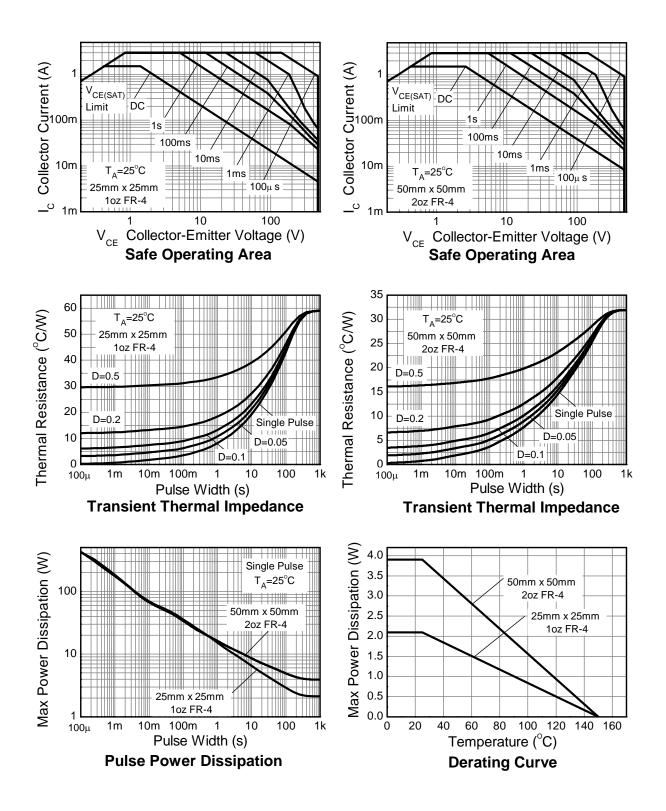
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. Pulse test for pulse width < 5ms, duty cycle ≤ 10%.
6. For a device mounted with the exposed collector pad on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
7. Same as note (6), except the device is surface mounted on 25mm x 25mm 2oz copper.
8. Same as note (6), except the device is surface mounted on 25mm x 25mm 1oz copper.
9. Same as note (6), except mounted on minimum recommended pad (MRP) layout.
10. Thermal resistence from involve or evidence of a condent of a condent or pad (MRP) layout.

Thermal resistance from junction to solder-point (on the exposed collector pad).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





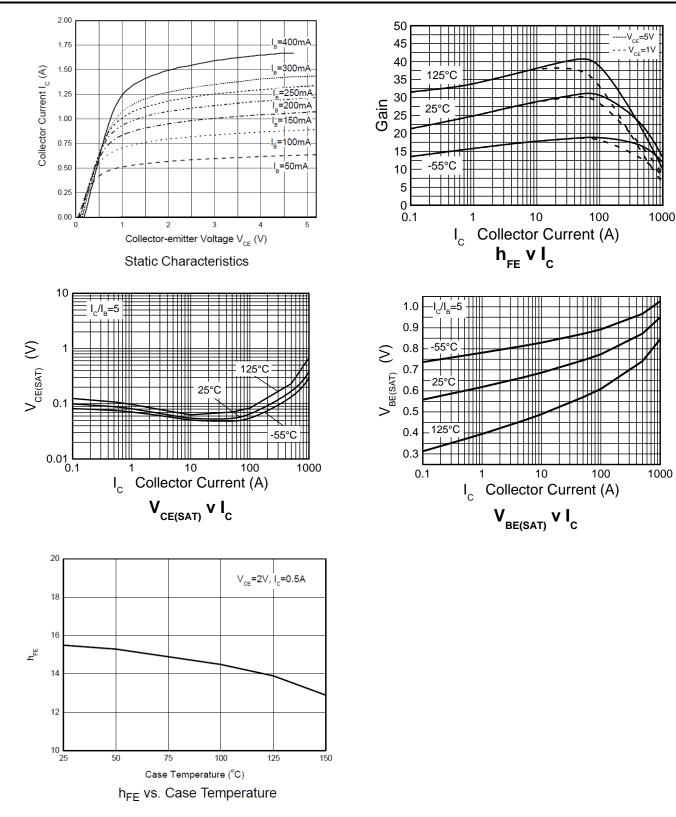
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV _{CES}	700	—	—	V	$I_{C} = 100 \mu A, V_{BE} = 0 V$
Collector-Emitter Breakdown Voltage	BV _{CEO}	460	—	—	V	I _C = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	9	—	_	V	I _E = 100μA
Collector Cutoff Current	I _{CEV}	_	—	10	μA	$V_{CE} = 700V, V_{BE} = -1.5V$
		15	_	—	_	$I_{C} = 0.3A, V_{CE} = 2V$
DC Current Transfer Static Ratio (Note 12)	h _{FE}	14	17	30	—	$I_{C} = 0.5A, V_{CE} = 2V$
		5	—	25	-	$I_{C} = 1.0A, V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 12)	Manual	_	0.17	0.3	V	$I_{\rm C} = 0.5 {\rm A}, \ I_{\rm B} = 0.1 {\rm A}$
Collector-Enniter Saturation Voltage (Note 12)	V _{CE(SAT)}	—	0.29	0.4		$I_{C} = 1A, I_{B} = 0.25A$
Base-Emitter Saturation Voltage (Note 12)	V _{BE(SAT)}		—	1.0	V	$I_{\rm C} = 0.5 {\rm A}, \ I_{\rm B} = 0.1 {\rm A}$
Dase-Emilier Saturation Voltage (Note 12)		—	—	1.2		$I_{C} = 1A, I_{B} = 0.25A$
Output Capacitance	C _{ob}	_	16	—	pF	$V_{CB} = 10V, f = 0.1MHz$
Transition Frequency	f _T	4	—	—	MHz	$I_{C} = 0.1A, V_{CE} = 10V$
Turn-on Time with Resistive Load	t _{ON}	_	0.43	_		
Storage Time with Resistive Load	ts	_	1.64	_	μs	$I_{C} = 1A, V_{CC} = 125V, I_{B1} = 0.2A,$ $I_{B2} = -0.2A$
Fall Time with Resistive Load	tF	_	0.28	_		IB20.20

Note: 12. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



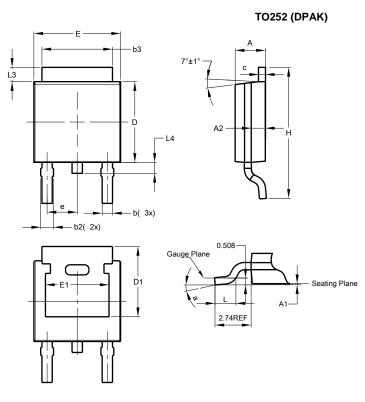
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

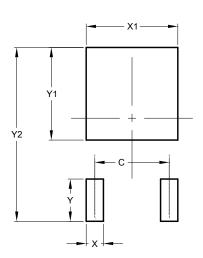
Please see http://www.diodes.com/package-outlines.html for the latest version.



		(DPA	()	
Dim	Min	Max	Тур	
Α	2.19	2.39	2.29	
A1	0.00	0.13	0.08	
A2	0.97	1.17	1.07	
b	0.64	0.88	0.783	
b2	0.76	1.14	0.95	
b3	5.21	5.46	5.33	
С	0.45	0.58	0.531	
D	6.00	6.20	6.10	
D1	5.21	1	_	
е	Ι	-	2.286	
Е	6.45	6.70	6.58	
E1	4.32	-	-	
Н	9.40	10.41	9.91	
L	1.40	1.78	1.59	
L3	0.88	1.27	1.08	
L4	0.64	1.02	0.83	
а	0°	10°	_	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252 (DPAK)

Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Y	2.600		
Y1	5.700		
Y2	10.700		

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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